NSN 5961-01-017-0390

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-017-0390 **Inclosure Material:** Glass **Overall Length:** 0.182 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.094 inches **Function For Which Designed:** Rectifier Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: